



TAYCHIPST

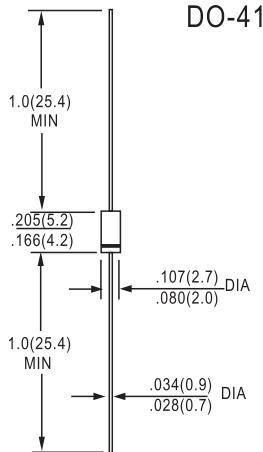
Glass Passivated Junction Fast Switching Rectifier

RGP02-12E THRU RGP02-20E

1200V-2000V 0.5A

**FEATURES**

- Plastic package has Underwriters Laboratories Flammability Classification 94V-0
- High temperature metallurgically bonded construction
- Capable of meeting environmental standards of MIL-S-19500
- For use in high frequency rectifier circuits
- Fast switching for high efficiency
- Cavity-free glass passivated junction
- 0.5 Ampere operation at TA=55°C with no thermal runaway
- Typical IR less than 0.2µA
- High temperature soldering guaranteed: 350°C/10 seconds, 0.375" (9.5mm) lead length, 5 lbs. (2.3kg) tension



Dimensions in inches and (millimeters)

**MECHANICAL DATA****Case:** Molded plastic over glass body**Terminals:** Plated axial leads, solderable per MIL-STD-750, Method 2026**Polarity:** Color band denotes cathode end**Mounting Position:** Any**Weight:** 0.012 oz., 0.3 g**MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS****Maximum Ratings & Thermal Characteristics**

Ratings at 25°C ambient temperature unless otherwise specified.

Parameter	Symbols	RGP02 -12E	RGP02 -14E	RGP02 -16E	RGP02 -18E	RGP02 -20E	Units
Maximum repetitive peak reverse voltage	V <sub>RRM</sub>	1200	1400	1600	1800	2000	V
Maximum RMS voltage	V <sub>RMS</sub>	840	980	1120	1260	1400	V
Maximum DC blocking voltage	V <sub>DC</sub>	1200	1400	1600	1800	2000	V
Maximum average forward rectified current 0.375" (9.5mm) lead length at TA=55°C	I <sub>F(AV)</sub>			0.5			A
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	I <sub>FSM</sub>			20			A
Typical thermal resistance <sup>(1)</sup>	R <sub>θJA</sub> R <sub>θJL</sub>			65 30			°C/W
Operating junction and storage temperature range	T <sub>J</sub> , T <sub>STG</sub>			-65 to +175			°C

**Electrical Characteristics**

Ratings at 25°C ambient temperature unless otherwise specified.

Maximum instantaneous forward voltage at 0.1A	V <sub>F</sub>	1.8	V
Maximum DC reverse current TA=25°C at rated DC blocking voltage TA=125°C	I <sub>R</sub>	5.0 50	µA
Maximum reverse recovery time at I <sub>F</sub> =0.5A, I <sub>R</sub> =1.0A, I <sub>rr</sub> =0.25A	t <sub>rr</sub>	300	ns
Typical junction capacitance at 4.0V, 1MHz	C <sub>J</sub>	5.0	pF

**Note:**

(1) Thermal resistance from junction to ambient and from junction to lead at 0.375" (9.5mm) lead length, P.C.B. mounted



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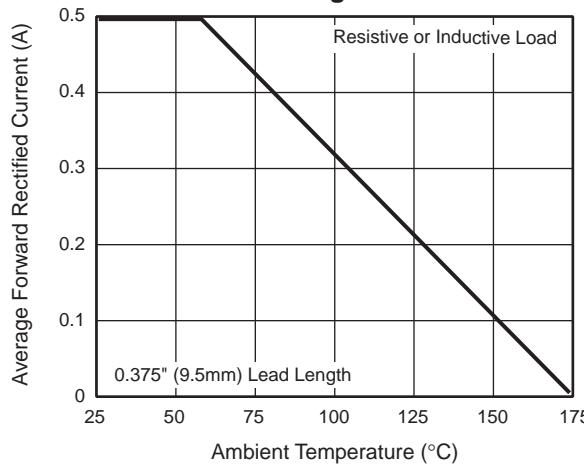
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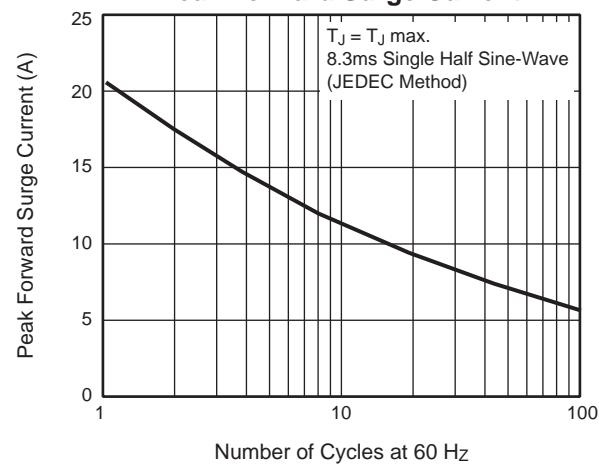
1200V-2000V 0.5A

## RATINGS AND CHARACTERISTIC CURVES RGP02-12E THRU RGP02-20E

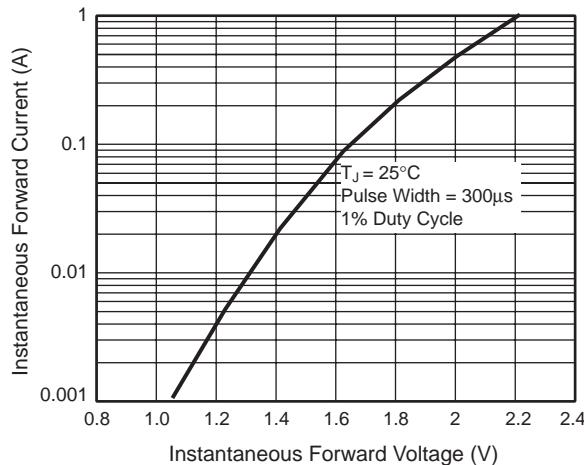
**Fig. 1 — Forward Current Derating Curve**



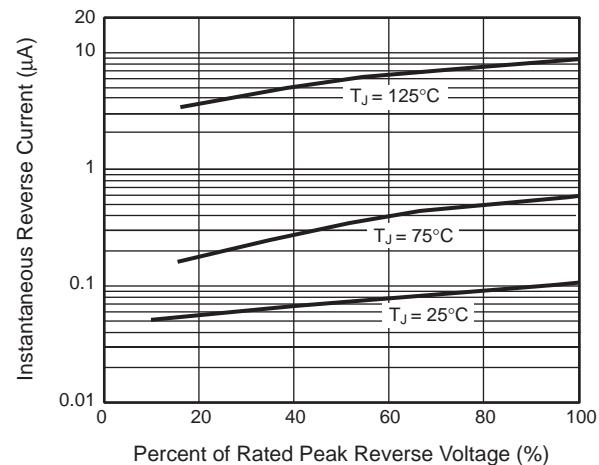
**Fig. 2 — Maximum Non-Repetitive Peak Forward Surge Current**



**Fig. 3 — Typical Instantaneous Forward Characteristics**



**Fig. 4 — Typical Reverse Characteristics**



**Fig. 5 — Typical Junction Capacitance**

